

# 0.5Ω Low-Voltage Dual SPDT Analog Switch

# UM4684H *CSP10 2.0×1.5* UM4684EEUE *MSOP10*

#### **General Description**

The UM4684 is a sub  $1\Omega$  (0.5 $\Omega$  at 2.7V) dual SPDT analog switch designed for low voltage applications.

The UM4684 has on-resistance matching(less than  $0.05\Omega$  at 2.7V) and flatness (less than  $0.2\Omega$  at 2.7V) that are guaranteed over the entire voltage range. Additionally, low logic thresholds make the UM4684 an ideal interface to low voltage DSP control signals.

The UM4684 has fast switching speed with break-before-make guaranteed. In the ON condition, all switching elements conduct equally in both directions. OFF-isolation and crosstalk is -69dB at 100kHz.

The UM4684 is built on high-density low voltage CMOS process, and contains the additional benefit of 2000V ESD protection.

As a committed partner to the community and the environment, Union manufactures this product with lead (Pb)-free device terminations.

#### **Applications**

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- Battery Operated Systems
- Relay Replacement
- Power Routing
- Communication Circuits

#### **Features**

- CSP10 & MSOP10 Packages
- ESD Protection >2000V
- +1.8V to +5.5V Single Supply Operation
- NC Switch  $R_{ON}$ :  $0.5\Omega$  (+2.7V Supply)
- NO Switch  $R_{ON}$ : 0.6 $\Omega$  (+2.7V Supply)
- R<sub>ON</sub> Match between Channels:  $0.05\Omega$  Max (+2.7V Supply)
- R<sub>ON</sub> Flatness over Signal Range: 0.2Ω Max (+2.7V Supply)
- 1.8V Logic Compatibility
- Low Crosstalk: -69dB (100kHz)
- High Off-Isolation: -69dB (100kHz)

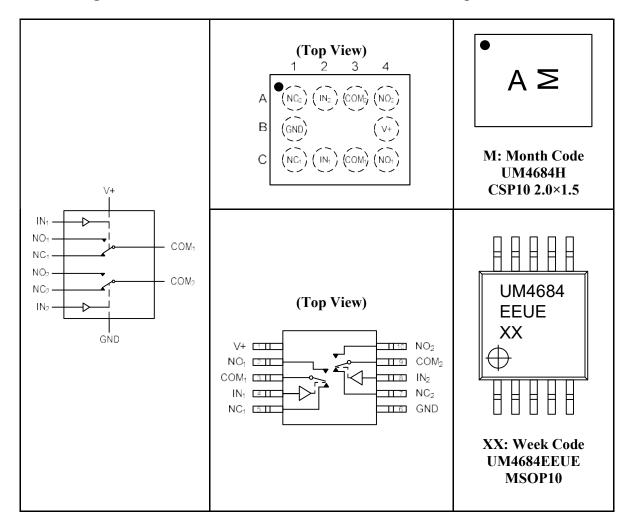
#### **Ordering Information**

Part Number	Temp. Range	Packaging Type	Marking Code	Shipping Qty
UM4684H	-40°C to 85°C	CSP10 2.0×1.5	A	3000pcs/7 Inch Tape & Reel
UM4684EEUE	-40°C to 85°C	MSOP10	UM4684EEUE	4000pcs/13 Inch Tape & Reel



## **Pin Configurations**

**Top View** 



**Ball Mapping for UM4684H** 

	1	2	3	4
Α	NC <sub>2</sub>	IN <sub>2</sub>	COM <sub>2</sub>	NO <sub>2</sub>
В	GND			V+
С	NC <sub>1</sub>	IN <sub>1</sub>	COM <sub>1</sub>	NO <sub>1</sub>

Transparent Top View



#### **Pin Description**

Pin Number		umber	
Name	CSP10 2.0×1.5	MSOP10	Function
NC_	A1, C1	5, 7	Analog Switch—Normally Closed Terminal
IN_	A2, C2	4, 8	Digital Control Input
COM_	A3, C3	3, 9	Analog Switch—Common Terminal
NO_	A4, C4	2, 10	Analog Switch—Normally Open Terminal
V+	В4	1	Positive Supply Voltage Input
GND	B1	6	Ground

#### **Function Table**

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

#### **Absolute Maximum Ratings (Note 1)**

Parameter	Value	Unit	
Voltage on V+ Pin (Reference to GND)		-0.3 to +6	V
Voltage on IN_, COM_, NC_, NO_ Pins (Reference to GND)	s (Note 2)	-0.3 to (V <sub>+</sub> +0.3)	V
Continuous Current (NO_, NC_, COM_	±300	mA	
Peak Current (Pulsed at 1 ms, 10% Duty	Cycle)	±500	mA
Storage Temperature		-65 to 150	°C
Package Solder Reflow Conditions	IR/Convection	250	°C
(Note 3)	>2	kV	
Power Dissipation (Packages) (Note 4)	CSP10 (Note 5)	457	mW

- Note 1: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- Note 2: Signals on NC\_, NO\_, or COM\_ or IN\_ exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- Note 3: Refer to IPC/JEDEC (J-STD-020B).
- Note 4: All bumps welded or soldered to PC Board.
- Note 5: Derate 5.7mW/°C above 70°C.



# Electrical Characteristics (V+=3V, $\pm 10\%$ deviation, V<sub>IN</sub>=0.5 or 1.4V (Note 6))

Parameter	Symbol	Test Conditions Otherwise Unless	rwice Unless   1emp		Limits 40°C to 85°	<b>C</b> )	Unit	
rarameter	Symbol	Specified	(Note 7)	Min (Note 9)	Typ (Note 8)	Max (Note 9)	Unit	
Analog Switch								
Analog Signal Range (Note 10)	$\begin{array}{c} V_{NO} \\ V_{NC} \\ V_{COM} \end{array}$		Full	0		$V_{+}$	V	
On-Resistance (Note 10)	Ron		Room Full		0.5	0.8 1.0		
R <sub>ON</sub> Flatness (Note 10)	R <sub>on</sub> Flatness	V <sub>+</sub> =2.7V, V <sub>COM</sub> =0.6/1.5V, I <sub>NO</sub> , I <sub>NC</sub> =100mA	Room			0.15	Ω	
On-Resistance Match Between Channels (Note 10)	$\Delta R_{DS(on)}$	Tho, the Toomia	Room			0.05		
Switch Off Leakage	$I_{NO(off)}, \ I_{NC(off)}$	V <sub>+</sub> =3.3V, V <sub>NO</sub> ,V <sub>NC</sub> =0.3V/3V,	Room Full	-2 -20		2 20		
Current	$I_{\text{COM(off)}}$	$V_{\text{COM}} = 3V/0.3V$	Room Full	-2 -20		2 20	nA	
Channel-On Leakage Current	I <sub>COM(on)</sub>	$V_{+}=3.3V, \ V_{NO}, V_{NC}=V_{COM} \ =0.3V/3V$	Room Full	-2 -20		2 20		
Digital Control								
Input High Voltage (Note 10)	$V_{\mathrm{INH}}$		Full	1.4			V	
Input Low Voltage	$V_{INL}$		Full			0.5		
Input Capacitance	$C_{IN}$		Full		10		pF	
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN}=0$ or $V_{+}$	Full	-1		1	μА	
Dynamic Character	istics							
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ =2.0V,	Room Full		52	82 90		
Turn-Off Time	t <sub>OFF</sub>	$R_L=50\Omega$ , $C_L=35pF$	Room Full		43	73 78	ns	
Break-Before-Make Time	$t_{ m d}$	$V_{NO}$ or $V_{NC}$ =2.0V, $R_L$ =50 $\Omega$ , $C_L$ =35pF	Full	1	6		ns	
Charge Injection (Note 10)	Q <sub>INJ</sub>	$C_L$ =1nF, $V_{GEN}$ =1.5V, $R_{GEN}$ =0 $\Omega$	Room		21		рC	
Off-Isolation (Note 10)	O <sub>IRR</sub>	$R_L$ =50 $\Omega$ , $C_L$ =5pF, f=100kHz	Room		-69		dB	
Crosstalk (Note 10)	$X_{TALK}$	1 TOORTIE	Room		-69			
-3dB Bandwidth	BW	$R_L=50\Omega$ , $C_L=5pF$	Room		20		MHz	



NO NC Off Capacitance (Note 10)	$\begin{array}{c} C_{NO(off)} \\ C_{NC(off)} \end{array}$	$V_{IN}=0$ or $V_+$ ,	Room Room		145 145		F
Channel On Capacitance (Note 10)	$\begin{array}{c} C_{NO(on)} \\ C_{NC(on)} \end{array}$	f=1MHz	Room Room		406 406		pF
Power Supply							
Power Supply Range	V <sub>+</sub>		Full	1.8		5.5	V
Power Supply Current	I+	V <sub>IN</sub> =0 or V <sub>+</sub>	Room Full		0.001	1.0 1.0	μА

- Note 6. V<sub>IN</sub>=input voltage to perform proper function.
- Note 7. Room=25°C, Full=as determined by the operating suffix.
- Note 8. Typical values are for design aid only, not guaranteed nor subjected to production testing.
- Note 9. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Note 10. Guaranteed by design, nor subjected to production testing.

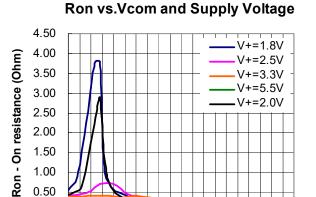


1.00

0.50

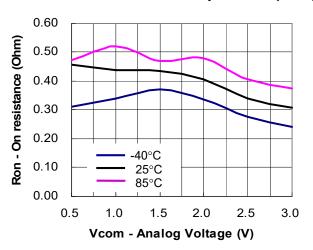
0.00

## **Typical Operating Characteristics**

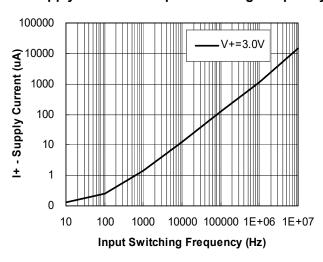


0.5 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 5.5 Vcom - Analog Voltage (V)

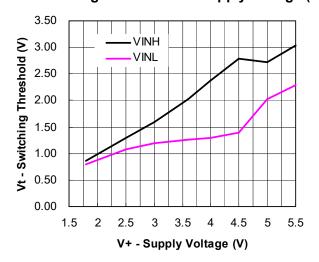
## Ron vs.Vcom and Temperature (NC1)



## **Supply Current vs. Input Switching Frequency**

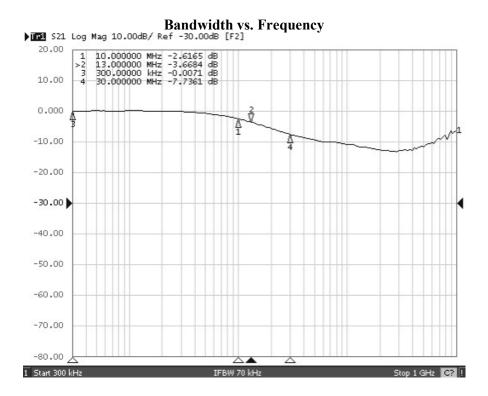


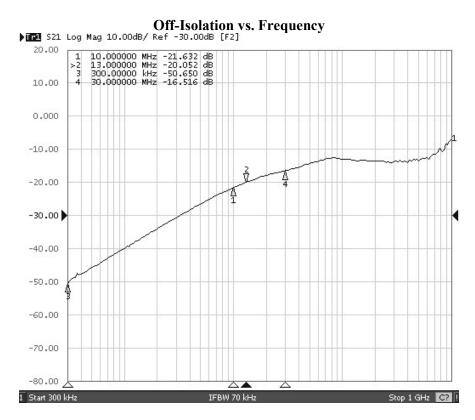
#### Switching Threshold vs. Supply Voltage (V)





## **Typical Operating Characteristics (Continued)**







## **Test Circuits/Timing Diagrams**

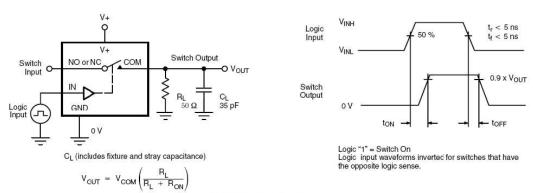


FIGURE 1. Switching Time

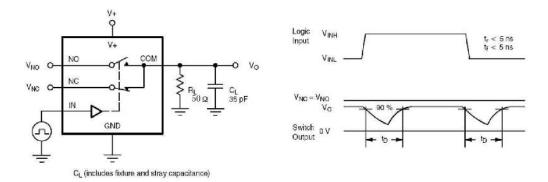


FIGURE 2. Break-Before-Make Interval

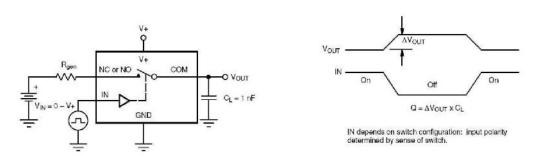


FIGURE 3. Charge Injection

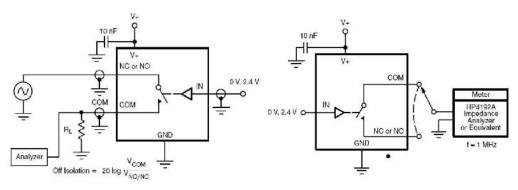


FIGURE 4. Off-Isolation

FIGURE 5. Channel Off/On Capacitance



#### **Applications Information**

#### **Digital Control Inputs**

The UM4684 logic inputs accept up to +5.5V regardless of supply voltage. For example, with a +3.3V supply, IN\_ may be driven low to GND and high to 5.5V. Driving IN\_ rail-to-rail minimizes power consumption. Logic levels for a +1.8V supply are 0.5V (low) and 1.4V (high).

#### **Analog Signal Levels**

Analog signals that range over the entire supply voltage (V+ to GND) is passed with very little change in on-resistance (see Typical Operating Characteristics). The switches are bidirectional, so the NO\_, NC\_, and COM\_ pins can be either inputs or outputs.

#### Caution

Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to devices.

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals, especially if the analog signal is not current limited. If this sequencing is not possible, and if the analog inputs are not current limited to <20mA, add a small signal diode (D1) as shown in Figure 6. Adding a protection diode reduces the analog range to a diode drop (about 0.7V) below V+ (for D1). RON increases slightly at low supply voltages. Maximum supply voltage (V+) must not exceed +6V. Protection diode D1 also protects against some over voltage situations. No damage will result on Figure 6's circuit if the supply voltage is below the absolute maximum rating applied to an analog signal pin.

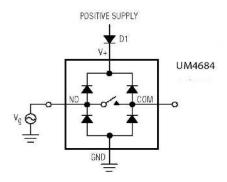


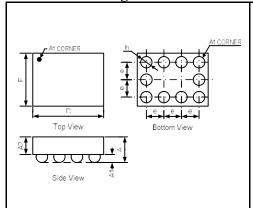
Figure 6



# **Package Information**

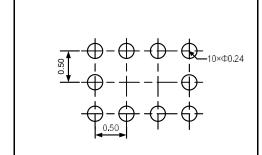
## UM4684H CSP10 2.0×1.5

**Outline Drawing** 



DIMENSIONS							
Crimbal	MILLIMETERS			INCHES			
Symbol	Min	Тур	Max	Min Typ I		Max	
A	0.68	0.72	0.76	0.027	0.028	0.030	
A1	0.21	0.231	0.24	0.0083	0.0091	0.0094	
A2	0.47	0.49	0.52	0.0185	0.0193	0.0205	
b	0.27	0.31	0.34	0.011	0.012	0.013	
D	2.00	-	2.10	0.079	-	0.083	
Е	1.50	-	1.60	0.059	_	0.063	
e	0.50BSC			(	0.020BSC		

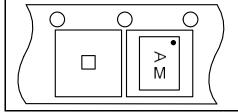
## **Land Pattern**



#### NOTES:

- 1. Bump is Lead Free Sn/Ag/Cu;
- 2. Unit: mm;
- 3. Non-solder mask defined copper landing pad;4. Laser Mark on silicon die back; back-lapped.

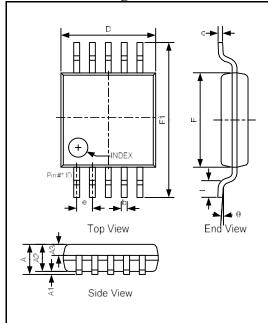
**Tape and Reel Orientation** 





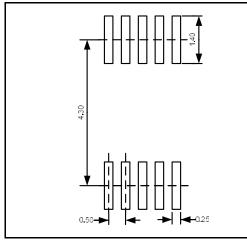
## **UM4684EEUE MSOP10**

**Outline Drawing** 



DIMENSIONS							
Cb al	MILLIMETERS			INCHES			
Symbol	Min	Тур	Max	Min	Тур	Max	
A	ı	1	1.10	1	1	0.043	
A1	0.00	1	0.15	0.000	-	0.006	
A2	0.75	0.85	0.95	0.030	0.033	0.037	
A3	0.25	0.35	0.39	0.010	0.014	0.015	
b	0.18	1	0.28	0.007	-	0.011	
c	0.09	1	0.23	0.004	-	0.009	
D	2.90	3.00	3.10	0.114	0.118	0.122	
Е	2.90	3.00	3.10	0.114	0.118	0.122	
E1	4.70	4.90	5.10	0.185	0.193	0.201	
e	0.50BSC		C	.020BS	$\Box$		
L	0.40	0.60	0.80	0.016	0.024	0.031	
θ	0°	-	8°	0°	-	8°	

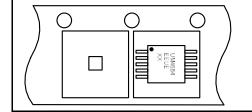
## **Land Pattern**



#### NOTES:

- 1. Compound dimension: 3.00×3.00;
- 2. Unit: mm;
- 3. General tolerance  $\pm 0.05$ mm unless otherwise specified;
- 4. The layout is just for reference.

**Tape and Reel Orientation** 





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